

Bipolar Transistors Silicon NPN/PNP Epitaxial Type (PCT Process)(Bias Resistor built-in Transistor)

## **RN4989**

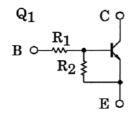
### 1. Applications

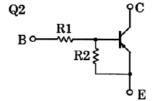
- · Switching
- · Inverter Circuits
- · Interfacing
- · Driver Circuits

#### 2. Features

- (1) AEC-Q101 qualified (Please see the orderable part number list)
- (2) Including two devices in US6 (ultra super mini type with 6 leads)
- (3) The integrated bias resistor reduces the number of external parts required, making it possible to reduce system size and assembly time.

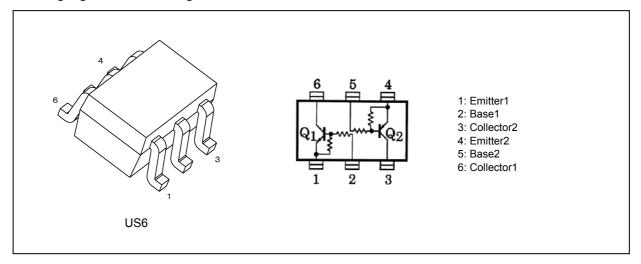
### 3. Equivalent Circuit





R1: 47 kΩ R2: 22 kΩ (Q1, Q2 Common)

### 4. Packaging and Pin Assignment



### 5. Orderable part number

| Orderable part number | AEC-Q101 |          | Note                    |  |  |
|-----------------------|----------|----------|-------------------------|--|--|
| RN4989,LF             | _        |          | General Use             |  |  |
| RN4989,LXGF           | YES      | (Note 1) | Unintended Use (Note 1) |  |  |
| RN4989,LXHF           | YES      |          | Automotive Use          |  |  |

Note 1: For more information, please contact our sales or use the inquiry form on our website.

Start of commercial production



## 6. Q1 Absolute Maximum Ratings (Note) (Unless otherwise specified, Ta = 25 °C)

| Characteristics           | Symbol           | Rating | Unit |
|---------------------------|------------------|--------|------|
| Collector-base voltage    | V <sub>CBO</sub> | 50     | V    |
| Collector-emitter voltage | V <sub>CEO</sub> | 50     |      |
| Emitter-base voltage      | V <sub>EBO</sub> | 15     |      |
| Collector current         | I <sub>C</sub>   | 100    | mA   |

### 7. Q2 Absolute Maximum Ratings (Note) (Unless otherwise specified, Ta = 25 °C)

| Characteristics           | Symbol           | Rating | Unit |
|---------------------------|------------------|--------|------|
| Collector-base voltage    | V <sub>CBO</sub> | -50    | V    |
| Collector-emitter voltage | V <sub>CEO</sub> | -50    |      |
| Emitter-base voltage      | V <sub>EBO</sub> | -15    |      |
| Collector current         | I <sub>C</sub>   | -100   | mA   |

# 8. Q1, Q2 Common Absolute Maximum Ratings (Note) (Unless otherwise specified, T<sub>a</sub> = 25 °C)

| Characteristics             | Symbol   | Rating           | Unit       |    |
|-----------------------------|----------|------------------|------------|----|
| Collector power dissipation | (Note 1) | P <sub>C</sub>   | 200        | mW |
| Junction temperature        |          | T <sub>j</sub>   | 150        | °C |
| Storage temperature         |          | T <sub>stg</sub> | -55 to 150 |    |

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note 1: Total rating

### 9. Q1 Electrical Characteristics (Unless otherwise specified, T<sub>a</sub> = 25 °C)

| Characteristics                      | Symbol               | Test Condition   | Min   | Тур. | Max   | Unit |
|--------------------------------------|----------------------|--|-------|------|-------|------|
| Collector cut-off current            | I <sub>CBO</sub>     | V <sub>CB</sub> = 50 V, I <sub>E</sub> = 0 mA            | _     | _    | 100   | nA   |
| Collector cut-off current            | I <sub>CEO</sub>     | V <sub>CE</sub> = 50 V, I <sub>B</sub> = 0 mA            | _     | 1    | 500   |      |
| Emitter cut-off current              | I <sub>EBO</sub>     | V <sub>EB</sub> = 15 V, I <sub>C</sub> = 0 mA            | 0.167 | -    | 0.311 | mA   |
| DC current gain                      | h <sub>FE</sub>      | V <sub>CE</sub> = 5 V, I <sub>C</sub> = 10 mA            | 70    | _    | _     |      |
| Collector-emitter saturation voltage | V <sub>CE(sat)</sub> | I <sub>C</sub> = 5 mA, I <sub>B</sub> = 0.25 mA          | _     | 0.1  | 0.3   | ٧    |
| Input voltage (ON)                   | V <sub>I(ON)</sub>   | $V_{CE} = 0.2 \text{ V}, I_{C} = 5 \text{ mA}$           | 2.2   | -    | 5.8   |      |
| Input voltage (off)                  | $V_{I(off)}$         | V <sub>CE</sub> = 5 V, I <sub>C</sub> = 0.1 mA           | 1.5   | _    | 2.6   |      |
| Transition frequency                 | f <sub>T</sub>       | V <sub>CE</sub> = 10 V, I <sub>C</sub> = 5 mA            | _     | 250  | _     | MHz  |
| Collector output capacitance         | C <sub>ob</sub>      | V <sub>CB</sub> = 10 V, I <sub>E</sub> = 0 mA, f = 1 MHz |       | 3    | 6     | pF   |



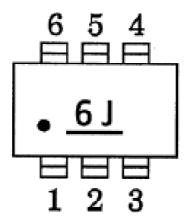
## 10. Q2 Electrical Characteristics (Unless otherwise specified, T<sub>a</sub> = 25 °C)

| Characteristics                      | Symbol               | Test Condition  | Min    | Тур. | Max    | Unit |
|--------------------------------------|----------------------|---|--------|------|--------|------|
| Collector cut-off current            | I <sub>CBO</sub>     | $V_{CB} = -50 \text{ V}, I_{E} = 0 \text{ mA}$                  | _      | _    | -100   | nA   |
| Collector cut-off current            | I <sub>CEO</sub>     | $V_{CE} = -50 \text{ V}, I_{B} = 0 \text{ mA}$                  | _      | _    | -500   |      |
| Emitter cut-off current              | I <sub>EBO</sub>     | V <sub>EB</sub> = -15 V, I <sub>C</sub> = 0 mA                  | -0.167 | -    | -0.311 | mA   |
| DC current gain                      | h <sub>FE</sub>      | $V_{CE} = -5 \text{ V}, I_{C} = -10 \text{ mA}$                 | 70     | _    |        | _    |
| Collector-emitter saturation voltage | V <sub>CE(sat)</sub> | $I_C = -5 \text{ mA}, I_B = -0.25 \text{ mA}$                   | _      | -0.1 | -0.3   | ٧    |
| Input voltage (ON)                   | V <sub>I(ON)</sub>   | $V_{CE}$ = -0.2 V, $I_{C}$ = -5 mA                              | -2.2   | -    | -5.8   |      |
| Input voltage (off)                  | $V_{I(off)}$         | $V_{CE} = -5 \text{ V}, I_{C} = -0.1 \text{ mA}$                | -1.5   | _    | -2.6   |      |
| Transition frequency                 | f <sub>T</sub>       | $V_{CE}$ = -10 V, $I_{C}$ = -5 mA                               | _      | 200  |        | MHz  |
| Collector output capacitance         | C <sub>ob</sub>      | $V_{CB} = -10 \text{ V}, I_E = 0 \text{ mA}, f = 1 \text{ MHz}$ | _      | 3    | 6      | pF   |

## 11. Q1, Q2 Common Electrical Characteristics (Unless otherwise specified, Ta = 25 °C)

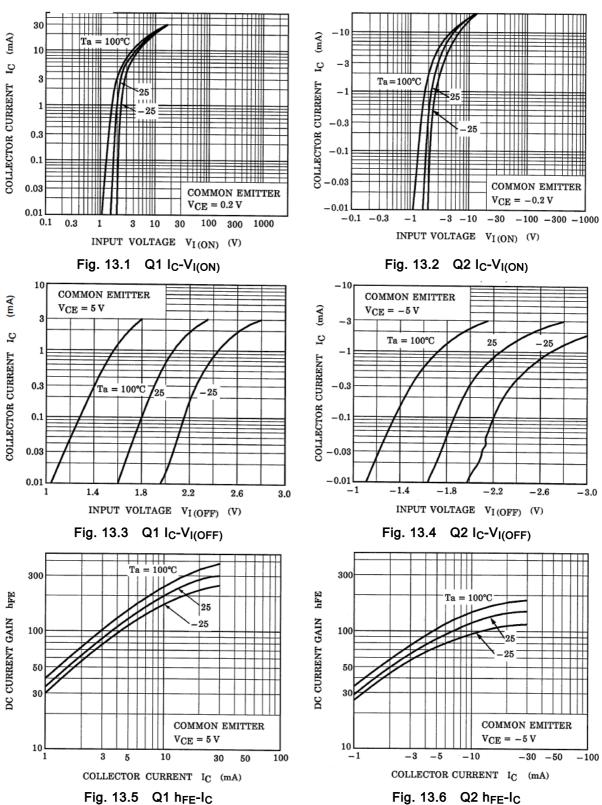
| Characteristics  | Symbol         | Test Condition | Min  | Тур. | Max  | Unit |
|------------------|----------------|----------------|------|------|------|------|
| Input resistance | R <sub>1</sub> | -              | 32.9 | 47   | 61.1 | kΩ   |
| Resistor ratio   | R1/R2          | -              | 1.92 | 2.14 | 2.35 | _    |

## 12. Marking





### 13. Characteristics Curves (Note)

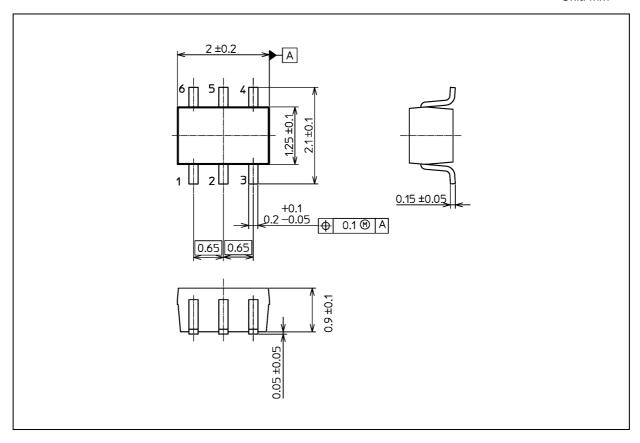


Note: The above characteristics curves are presented for reference only and not guaranteed by production test, unless otherwise noted.



### **Package Dimensions**

Unit: mm



Weight: 6.8 mg (typ.)

|                 | Package Name(s) |
|-----------------|-----------------|
| TOSHIBA: 1-2T1S |                 |
| Nickname: US6   |                 |



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